

Selection Guide

Part No.	Dice	Lens Type	Iv (ucd) [1] @ 10mA		Description
			Min.	Typ.	
CA25-11YWA	YELLOW (GaAsP/GaP)	WHITE DIFFUSED	1200	4850	Common Anode

Note:
1. Luminous Intensity / Luminous Flux: +/-15%.

Electrical / Optical Characteristics at TA=25°C

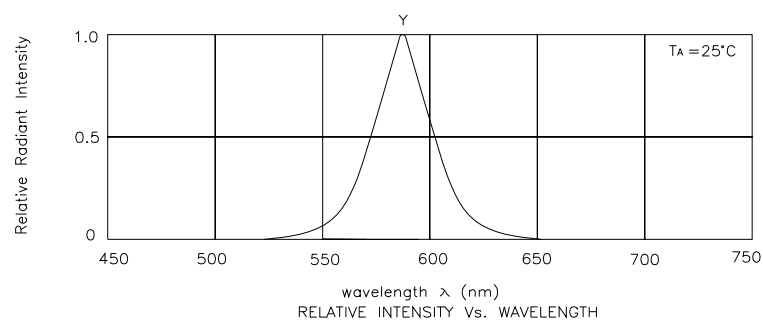
Symbol	Parameter		Device	Typ.	Max.	Units	Test Conditions
λ _{peak}	Peak Wavelength		Yellow	590		nm	I _F =20mA
λ _D [1]	Dominant Wavelength		Yellow	588		nm	I _F =20mA
Δλ _{1/2}	Spectral Line Half-width		Yellow	35		nm	I _F =20mA
C	Capacitance		Yellow	20		pF	V _F =0V;f=1MHz
V _F [2]	Forward Voltage	Dig1'8,'Dig2'8',Dig3'8',Dig4'8' D1,D4,D5,D6,D8	Yellow	2.1	2.5	V	I _F =20mA
		D2,D3,D7,L					
I _R	Reverse Current	Dig1'8,'Dig2'8',Dig3'8',Dig4'8' D1,D4,D5,D6,D8	Yellow		10	uA	V _R = 5V
		D2,D3,D7,L			20		

Notes:
1.Wavelength: +/-1nm.
2. Forward Voltage: +/-0.1V.

Absolute Maximum Ratings at TA=25°C

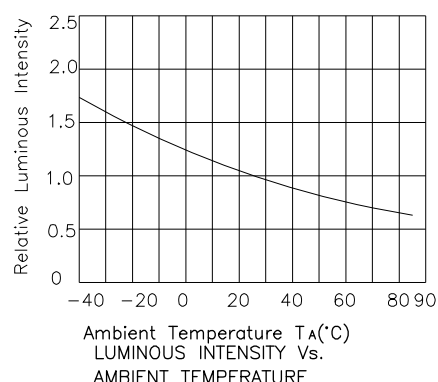
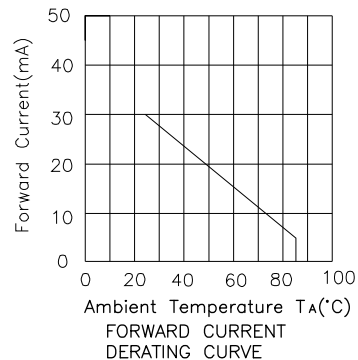
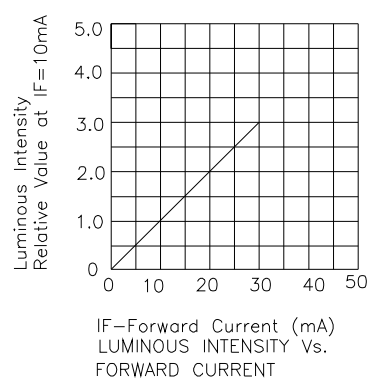
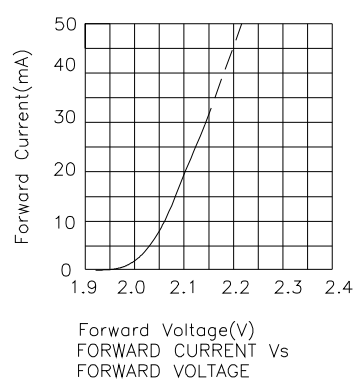
Parameter		Yellow	Units
Power dissipation	Dig1'8,'Dig2'8',Dig3'8',Dig4'8' D1,D4,D5,D6,D8	75	mW
	D2,D3,D7,L	150	
DCForward Current	Dig1'8,'Dig2'8',Dig3'8',Dig4'8' D1,D4,D5,D6,D8	30	mA
	D2,D3,D7,L	60	
Reverse Voltage	Dig1'8,'Dig2'8',Dig3'8',Dig4'8' D1,D4,D5,D6,D8	5	V
	D2,D3,D7,L		
PeakForward Current [1]	Dig1'8,'Dig2'8',Dig3'8',Dig4'8' D1,D4,D5,D6,D8	140	mA
	D2,D3,D7,L	280	
Operating/Storage Temperature		-40°C To +85°C	
Lead Solder Temperature [2]		260°C For 3~5 Seconds	

Notes:
1.1/10 Duty Cycle, 0.1ms Pulse Width.
2. 2mm below package base.

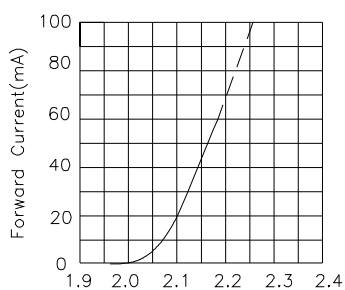


Yellow

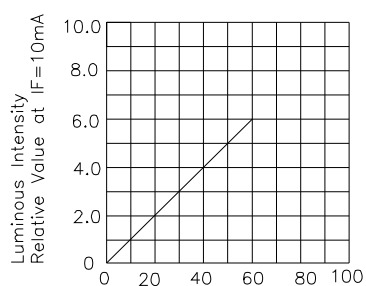
CA25-11YWA



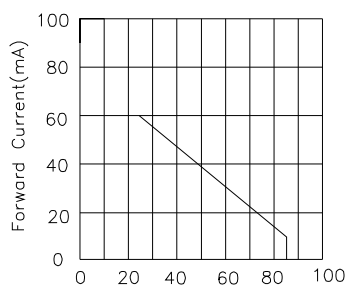
Yellow



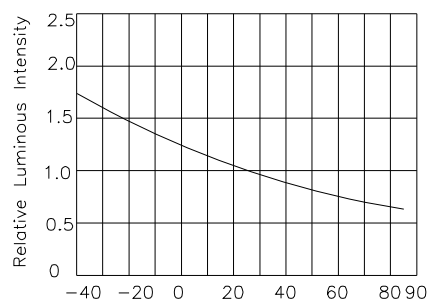
Forward Voltage(V)
FORWARD CURRENT Vs.
FORWARD VOLTAGE



I_F -Forward Current (mA)
LUMINOUS INTENSITY Vs.
FORWARD CURRENT



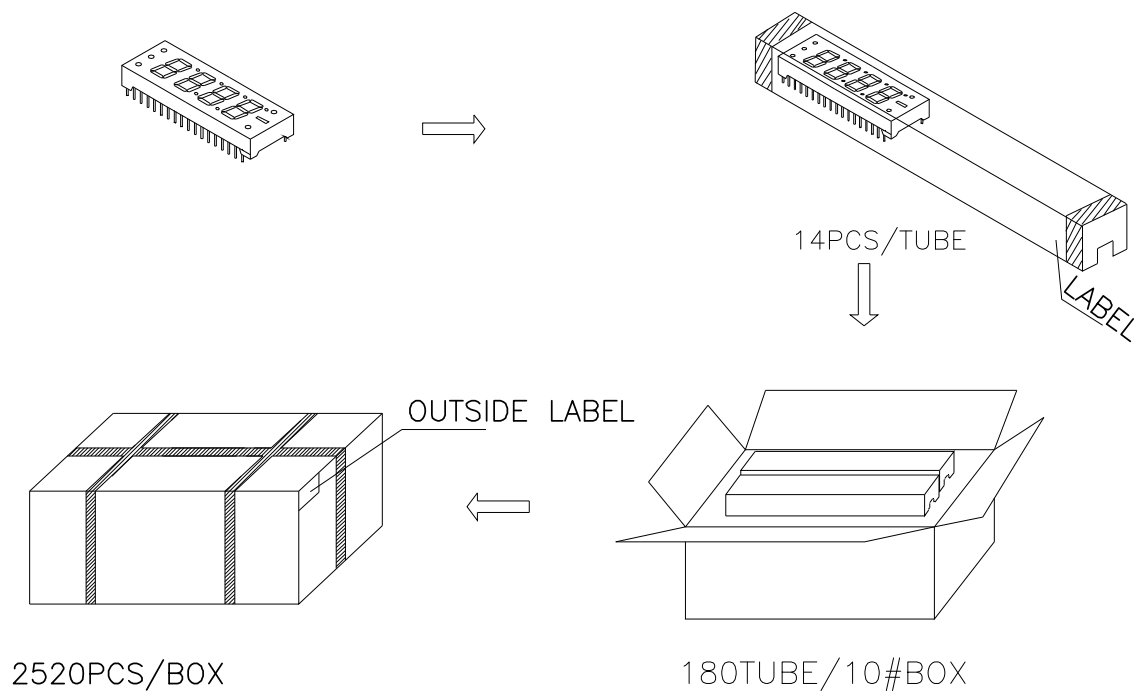
Ambient Temperature T_A (°C)
FORWARD CURRENT
DERATING CURVE



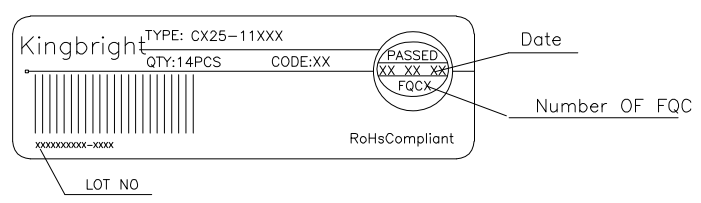
Ambient Temperature T_A (°C)
LUMINOUS INTENSITY Vs.
AMBIENT TEMPERATURE

PACKING & LABEL SPECIFICATIONS

CA25-11YWA



Inside LABEL Paste On The IC-tube



Outside LABEL Paste On The Box

